

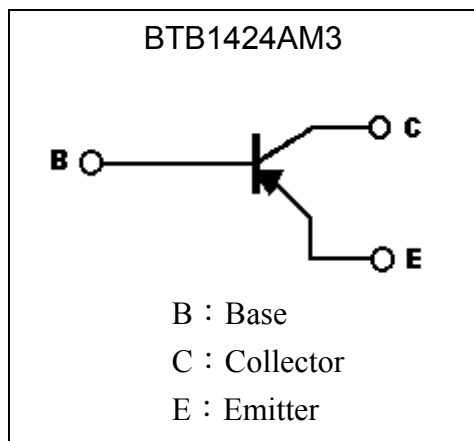
Low $V_{CE(sat)}$ PNP Epitaxial Planar Transistor

BTB1424AM3

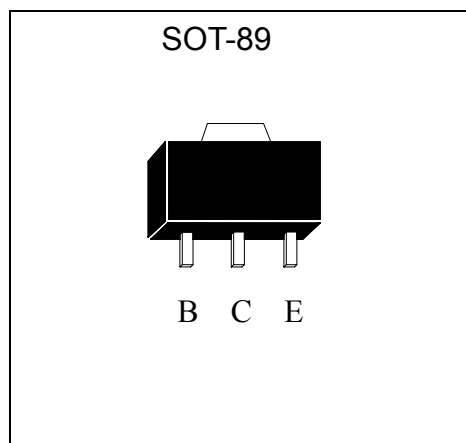
Features

- Excellent DC current gain characteristics
- Low Saturation Voltage, $V_{CE(sat)} = -0.3V(\text{typ})$ @ $I_C = -2A$, $I_B = -100mA$.
- Complementary to BTB2150AM3
- Pb-free package

Symbol



Outline



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V_{CBO}	-50	V
Collector-Emitter Voltage	V_{CEO}	-50	V
Emitter-Base Voltage	V_{EBO}	-6	V
Collector Current(DC)	I_C	-3	A
Collector Current(Pulsed) (Note 1)	I_{CP}	-5	
Power Dissipation	P_d	600	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55~+150	$^\circ\text{C}$

Note 1: Single pulse, $P_w \leq 10\text{ms}$, Duty Cycle $\leq 30\%$.

Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CBO}	-50	-	-	V	$I_C = -50\mu A$
BV_{CEO}	-50	-	-	V	$I_C = -1mA$
BV_{EBO}	-6	-	-	V	$I_E = -50\mu A$
I_{CBO}	-	-	-0.1	μA	$V_{CB} = -20V$
I_{EBO}	-	-	-0.1	μA	$V_{EB} = -5V$
$*V_{CE(sat)}$	-	-	-0.4	V	$I_C = -1A, I_B = -50mA$
$*V_{CE(sat)}$	-	-	-0.5	V	$I_C = -2A, I_B = -100mA$
$*h_{FE}$	82	-	560	-	$V_{CE} = -2V, I_C = -500mA$
f_T	-	240	-	MHz	$V_{CE} = -2V, I_C = -500mA, f = 100MHz$
C_{ob}	-	35	-	pF	$V_{CB} = -10V, f = 1MHz$

*Pulse Test: Pulse Width $\leq 380\mu s$, Duty Cycle $\leq 2\%$

Classification Of h_{FE}

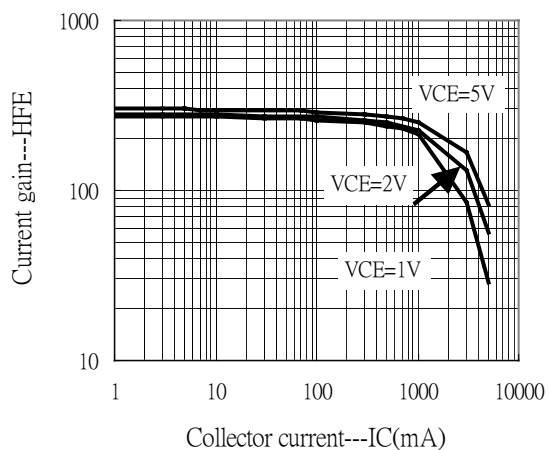
Rank	P	Q	R	S
h_{FE} range	82~180	120~270	180~390	270~560

Ordering Information

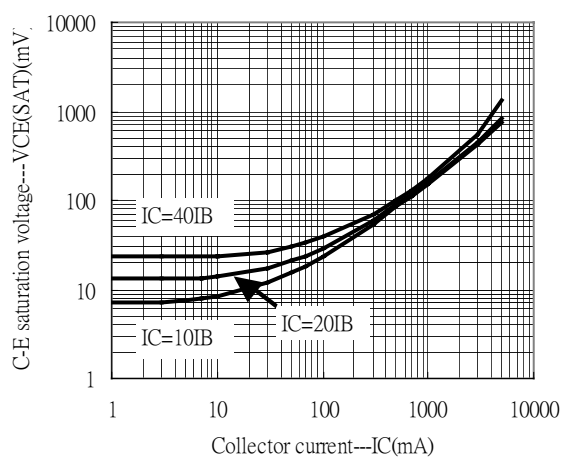
Device	Package	Shipping	Marking
BTB1424AM3	SOT-89 (Pb-free)	1000 pcs / Tape & Reel	AE

Characteristic Curves

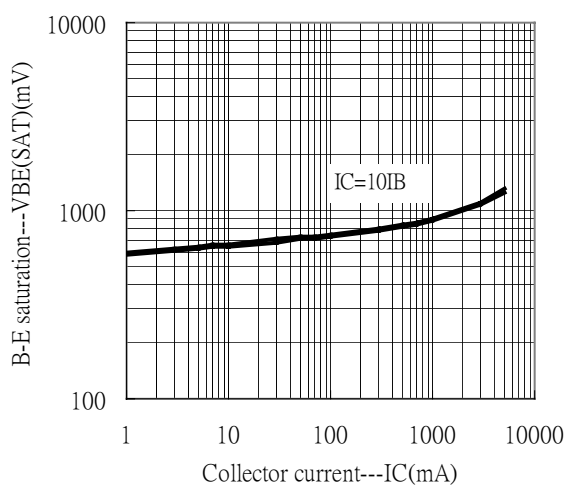
Current gain vs Collector current



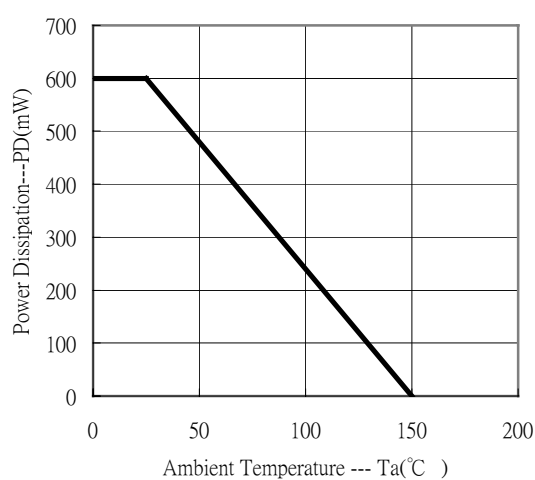
C-E saturation voltage vs Collector current



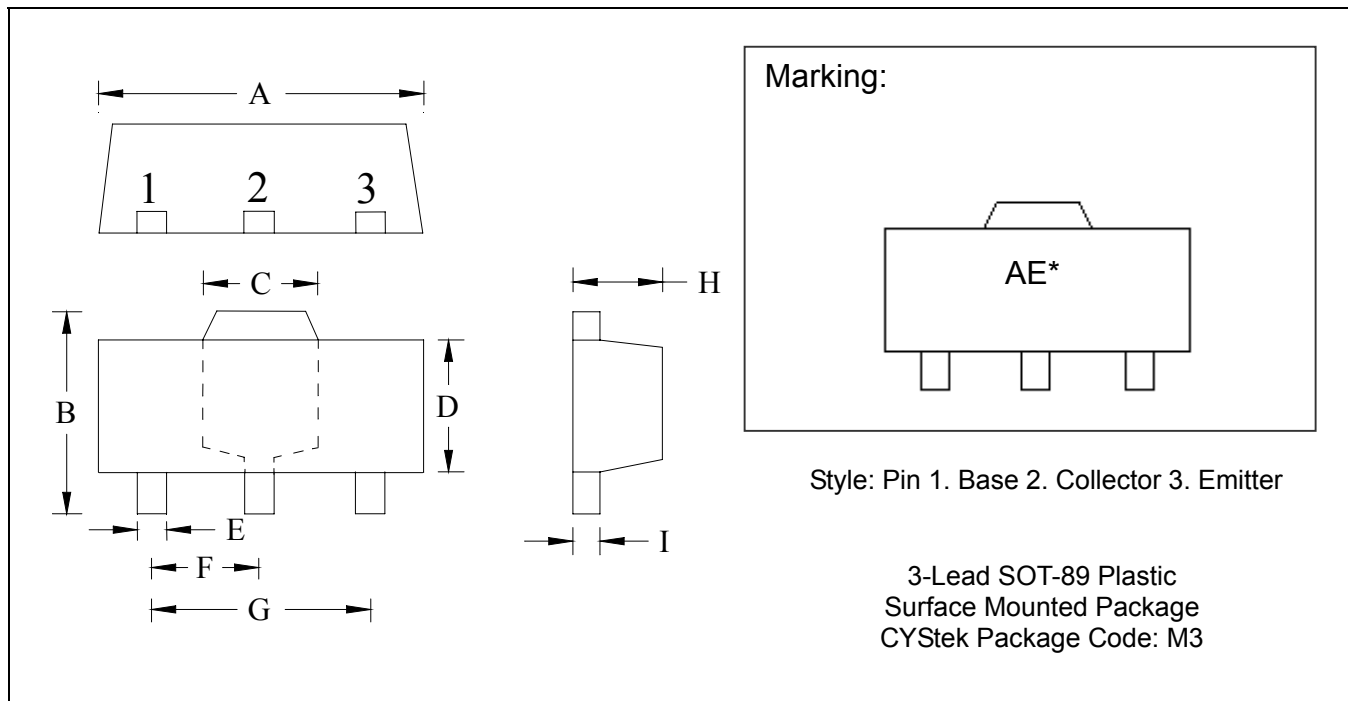
B-E saturation voltage vs Collector current



Power Derating Curve



SOT-89 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1732	0.1811	4.40	4.60	F	0.0583	0.0598	1.48	1.527
B	0.1594	0.1673	4.05	4.25	G	0.1165	0.1197	2.96	3.04
C	0.0591	0.0663	1.50	1.70	H	0.0551	0.0630	1.40	1.60
D	0.0945	0.1024	2.40	2.60	I	0.0138	0.0161	0.35	0.41
E	0.01417	0.0201	0.36	0.51					

Notes: 1.Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: 42 Alloy ; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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